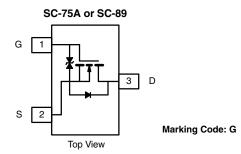
COMPLIANT

FREE



N-Channel 1.5 V (G-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (mA)			
20	5 at V _{GS} = 4.5 V	200			
	7 at V _{GS} = 2.5 V	175			
	9 at V _{GS} = 1.8 V	150			
	10 at V _{GS} = 1.5 V	50			



Ordering Information:

Si1032R-T1-GE3 (SC-75A, Lead (Pb)-free and Halogen-free) Si1032X-T1-GE3 (SC-89, Lead (Pb)-free -free Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Low-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns
- TrenchFET[®] Power MOSFETs: 1.5 V Rated
- 2000 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- · Low-Voltage Operation
- High-Speed Circuits
- · Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- · Battery Operated Systems
- · Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

ABSOLUTE MAXIMUM RATINGS $(T_A = 2)$			Si1032R		Si1032X		
Parameter	Symbol	5 s	Steady State	5 s	Steady State	Unit	
Drain-Source Voltage	V_{DS}	20				V	
Gate-Source Voltage		V_{GS}	± 6				
0 "	T _A = 25 °C	,	200	140	210	200	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C	I _D	110	100	150	140	
Pulsed Drain Current ^a		I _{DM}	500		600		mA
Continuous Source Current (Diode Conduction) ^a		I _S	250	200	300	240	
	T _A = 25 °C		280	250	340	300	- mW
Maximum Power Dissipation ^a for SC-75	T _A = 85 °C		145	130	170	150	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000				V

Notes:

a. Surface mounted on FR4 board.

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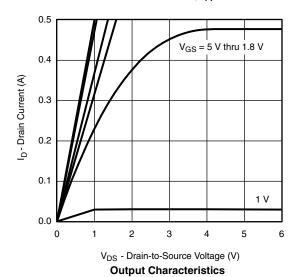
SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.40	0.7	1.2	V	
Cata Bady Laglaga	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$	± 0.5 ± 1.0		± 1.0		
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 1.0	± 3.0		
Zero Gate Voltage Drain Current		V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ	
	IDSS	V_{DS} = 20 V, V_{GS} = 0 V, T_{J} = 55 °C			10	1	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	250			mA	
		$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			5	Ω	
	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 175 \text{ mA}$			7		
Drain-Source On-State Resistance ^a		$V_{GS} = 1.8 \text{ V}, I_D = 150 \text{ mA}$			9		
		$V_{GS} = 1.5 \text{ V}, I_D = 40 \text{ mA}$			10		
Forward Transconductance ^a	g _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 200 \text{ mA}$		0.5		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 150 mA, V _{GS} = 0 V			1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			750			
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 250 \text{ mA}$		75		рС	
Gate-Drain Charge	Q_{gd}			225		1	
Turn-On Delay Time	t _{d(on)}				50		
Rise Time	t _r	V_{DD} = 10 V, R_L = 47 Ω			25	ne	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 200 \text{ mA}, V_{GEN} = 4.5 \text{ V}, R_g = 10 \Omega$			50	ns	
Fall Time	t _f				25		

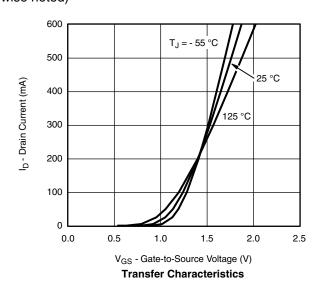
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

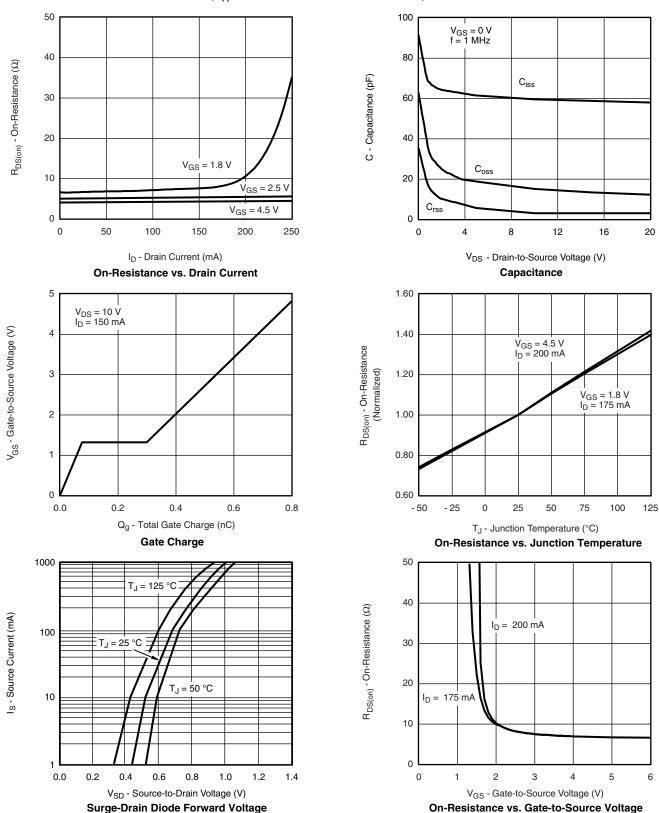
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)





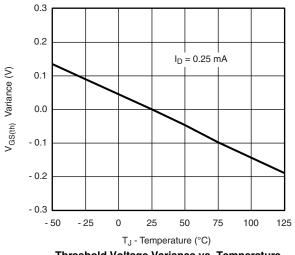


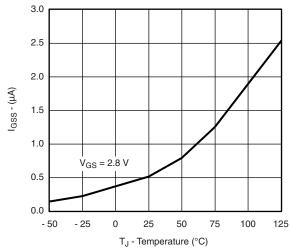
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



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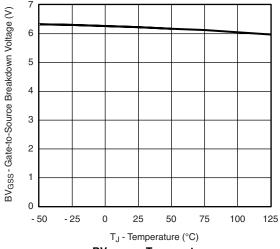
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



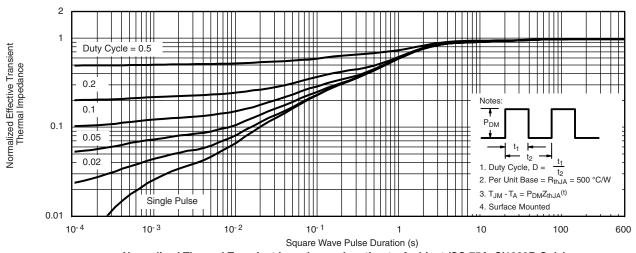


Threshold Voltage Variance vs. Temperature









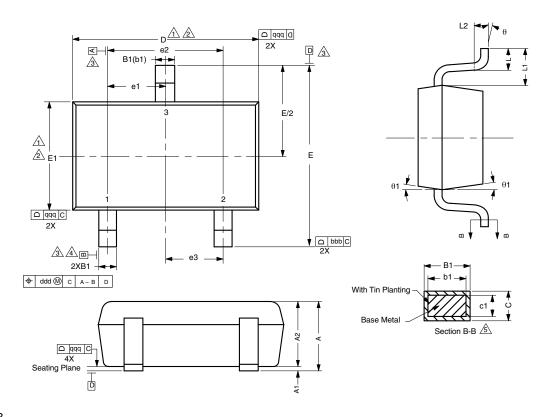
Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A, Si1032R Only)

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppq?71172.

www.vishay.com



SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

- Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- ②Datums A, B and D to be determined 0.10 mm from the lead tip.

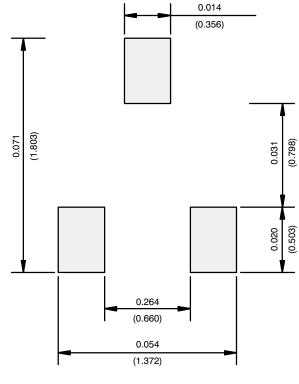
 4\text{Terminal positions are shown for reference only.}
- These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.10		

DIM.	N	NOTE		
Dilvi.	MIN.	NOM.	MAX.	NOTE
Α	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17	-	0.21	
С	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
Е	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1	0.50 BSC			
e2	1.00 BSC			
e3	0.50 BSC			
L	0.15	0.205	0.30	
L1	0.40 ref.			
L2	0.15 BSC			
q	0°	-	8°	
q1	4°	-	10°	



RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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